

Features

- Frequency Range DC-14GHz
- 48.5dBm Nominal P_{3dB} Pulsed
- Maximum PAE at 6GHz of 72%
- 17.8dB Linear Gain at 6GHz
- Drain Bias 28V
- Technology: GaN on SiC
- Lead-free and RoHS compliant
- Chip Dimensions: 0.824 x 2.495 x 0.10mm

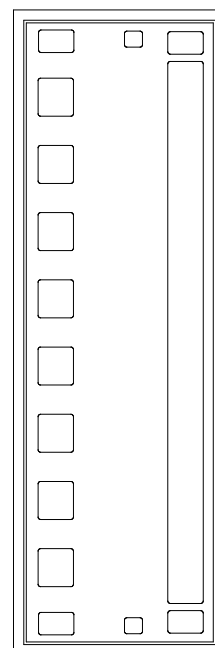
Applications

- Aerospace & Defense
- Broadband Wireless

Description

The ICPB1010 is a GaN on SiC discrete HEMT that operates from DC-14GHz. The design is optimized for power and efficiency using field plate technology.

Image



RF Performance | Simulated Conditions unless otherwise stated | $T_A=25^\circ\text{C}$, $V_D=28\text{V}$, Pulse width = 100uS, Duty cycle = 10%

Parameter	Units	Typical			
Frequency	GHz	3	6	10	14
Output Power P_{3dB}	dBm	48.3	48.5	48.5	48.6
Bias Current	mA	200	200	200	200
PAE @ P_{3dB}	%	74.6	72	65	55.8
Gain @ P_{3dB}	dB	19.8	14.8	9.7	6.1

Recommended operating conditions

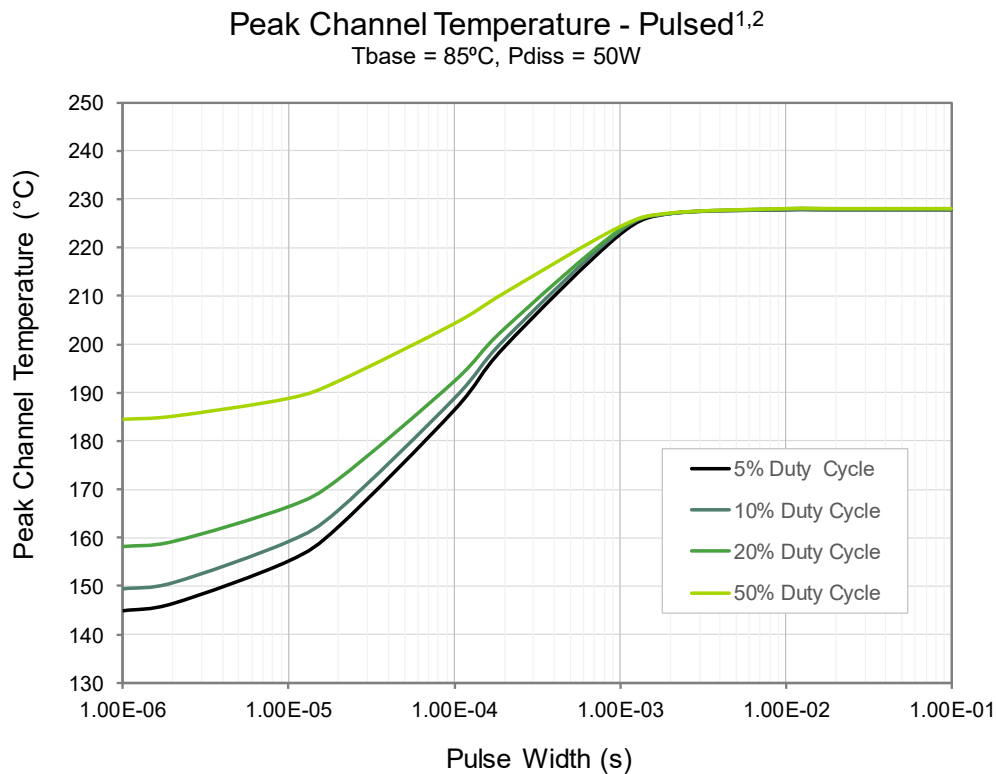
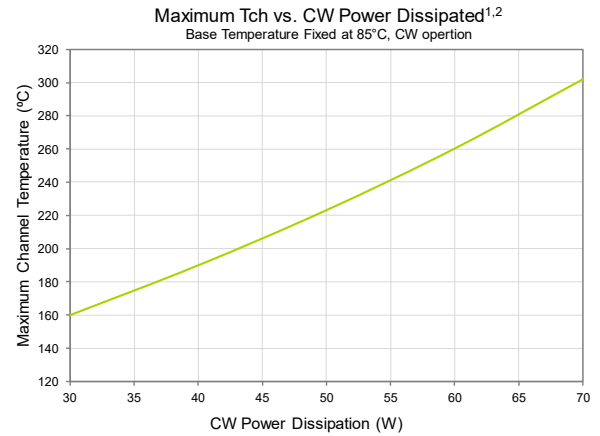
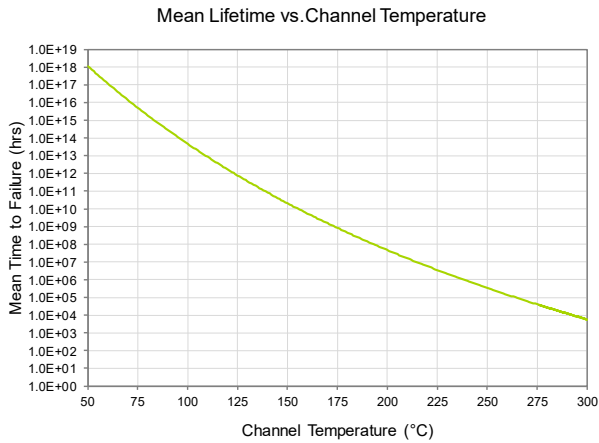
Parameter	Value
Drain Voltage (V_{DG})	12-32 V
Drain Quiescent Current (I_D)	0.2-0.5A
Drain current RF Drive (I_D)	4A
Gate Voltage (V_G)	-2.6V
Power Dissipation (CW)	56W
Channel Temperature (Max)	225°C

Absolute Maximum Ratings

Parameter	Absolute Maximum
Drain to Gate Voltage (V_{DG})	80 V
Gate Voltage Range (V_G)	-20V to 0V
Gate Current (I_G)	-10 to 30mA
Power Dissipation (CW)	63W
CW Input Power	+40dBm
Channel Temperature	275°C
Storage Temperature	-65°C to +150°C

Exceeding any one or combination of these limits may cause permanent damage to this device. ICONIC RF does not recommend sustained operation near these survivability limits.

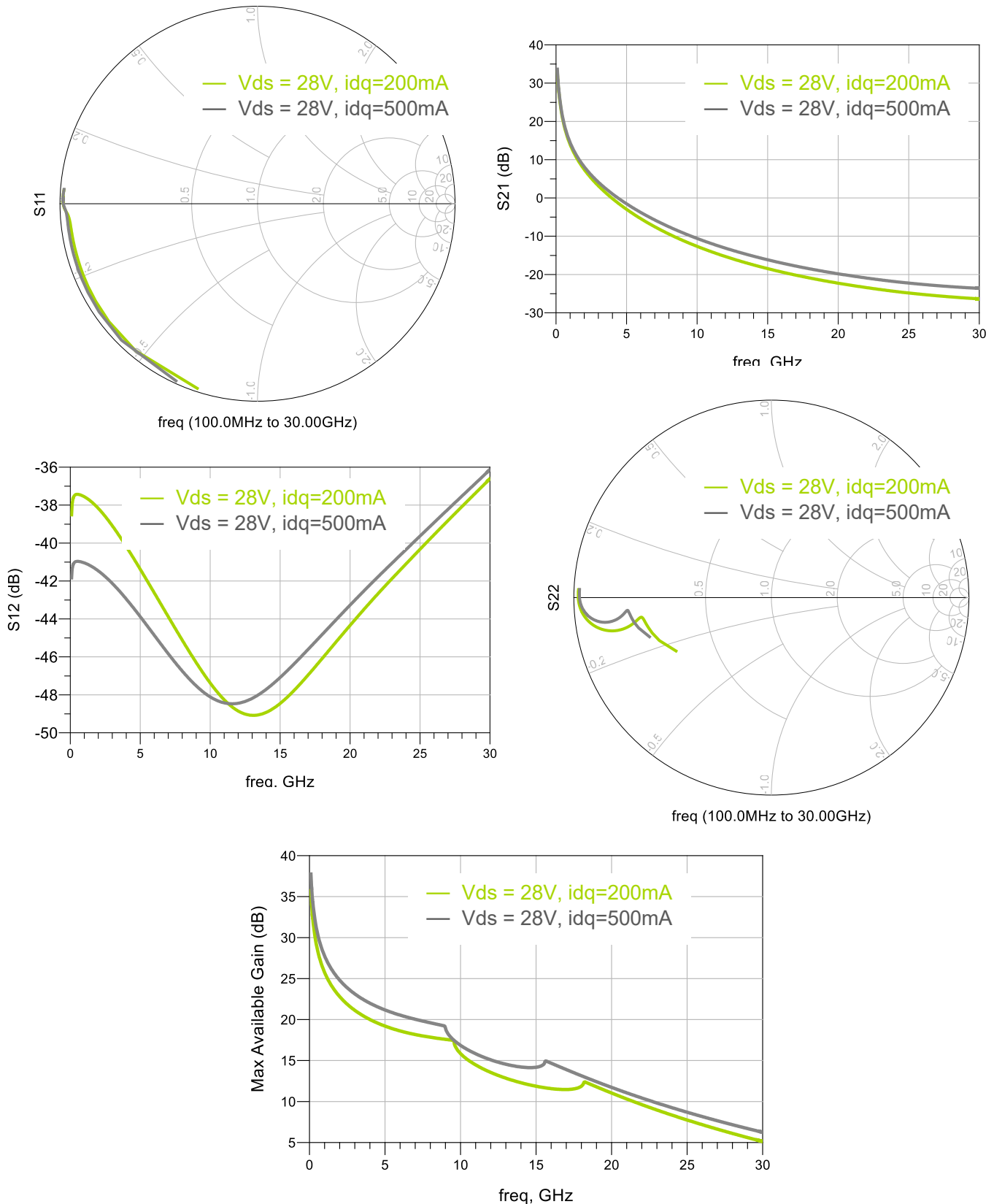
Thermal and Reliability



Notes

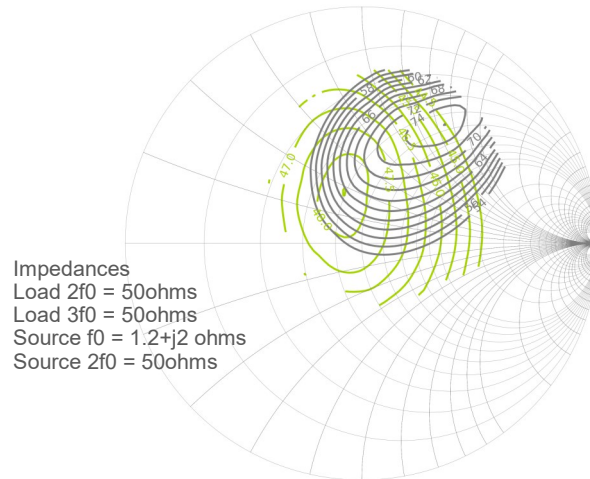
1. Assumes silver sintered epoxy attach (15um thick) and mounted on CuMo carrier
2. Base temperature is assumed at the top of the CuMo carrier

Model S-parameters | $T_A = 25^\circ\text{C}$



Model Load Pull Data 3GHz

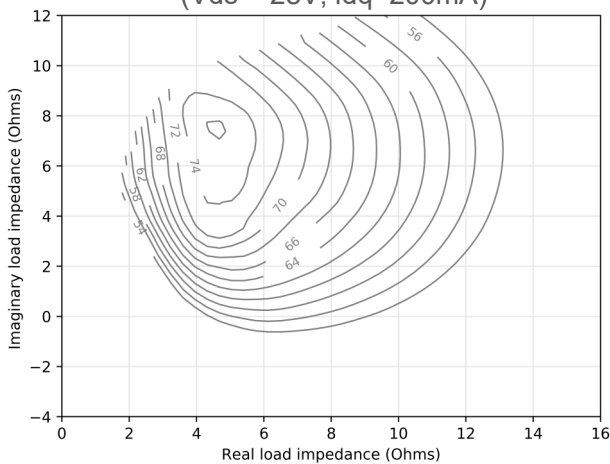
P3dB Output Power and PAE contours
(Vds = 28V, idq=200mA, Z0=50ohms)



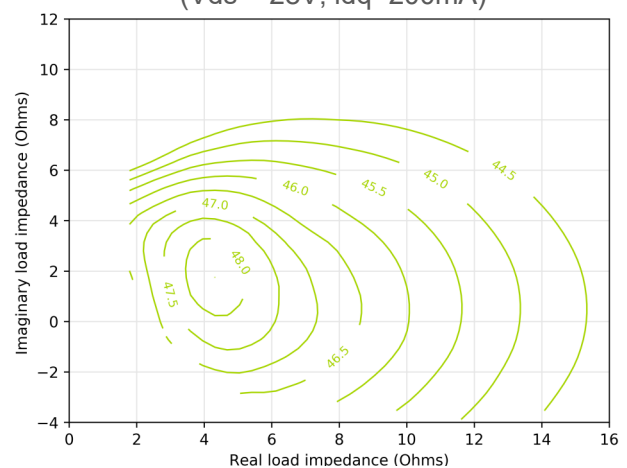
Max PAE = 74.5%
at Zload = 4.3+j7 ohms

Max Power = 48.3dBm
at Zload = 4.2+j1.8 ohms

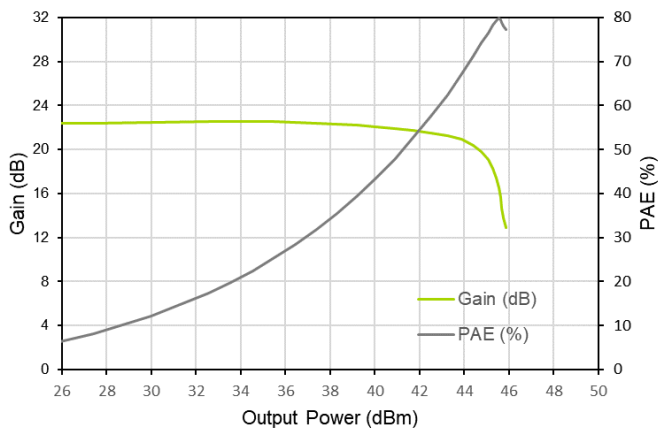
P3dB PAE contours
(Vds = 28V, idq=200mA)



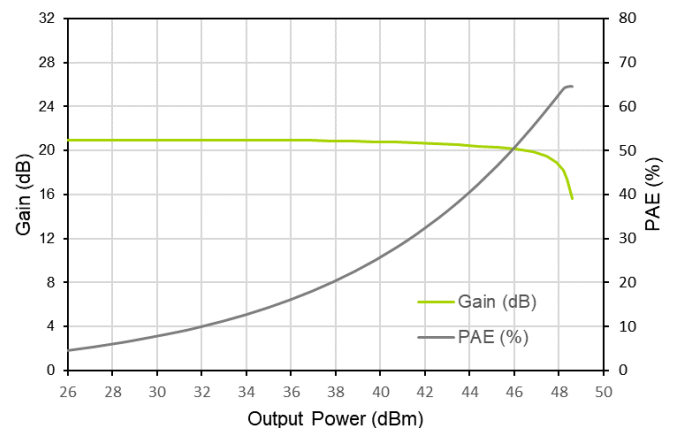
P3dB Output Power contours
(Vds = 28V, idq=200mA)



Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max PAE tune)

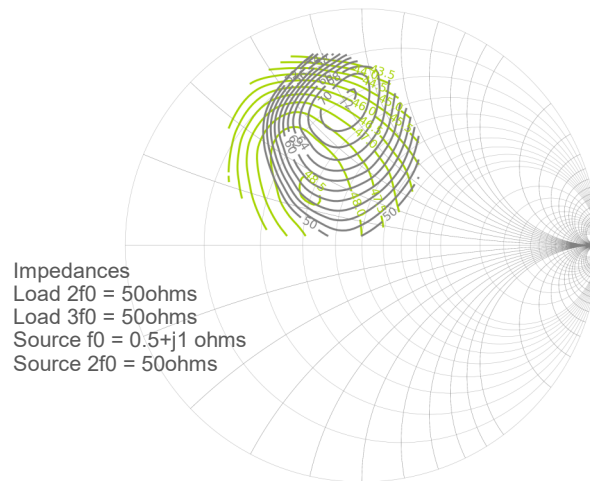


Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max Power tune)



Model Load Pull Data 6GHz

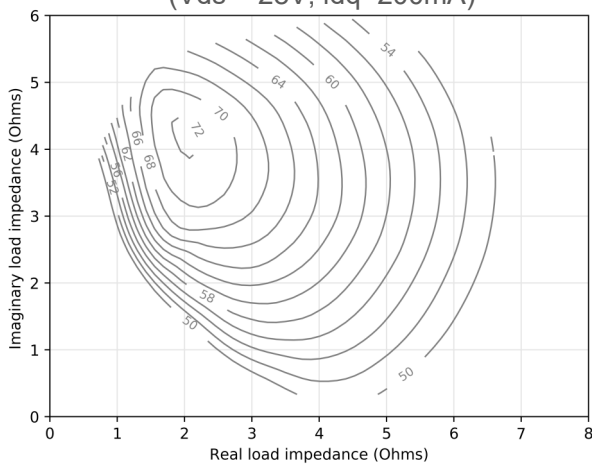
P3dB Output Power and PAE contours
(Vds = 28V, idq=200mA, Z0=50ohms)



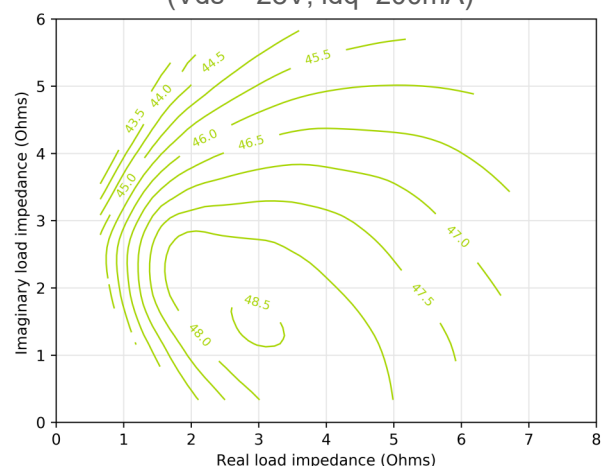
Max PAE = 72%
at Zload = 2.1+j4.2 ohms

Max Power = 48.5dBm
at Zload = 3+j1.4 ohms

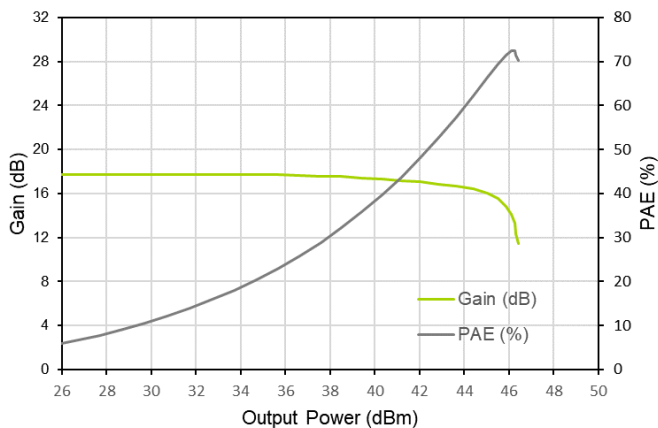
P3dB PAE contours
(Vds = 28V, idq=200mA)



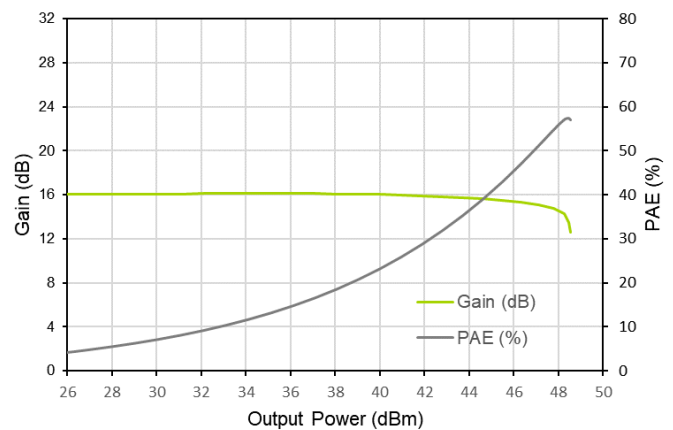
P3dB Output Power contours
(Vds = 28V, idq=200mA)



Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max PAE tune)

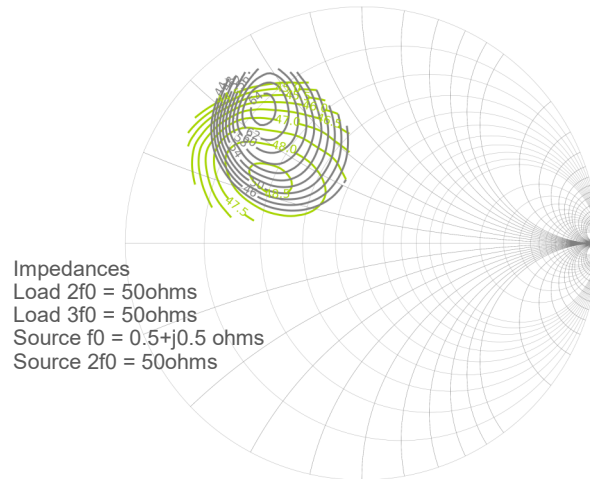


Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max Power tune)



Model Load Pull Data 10GHz

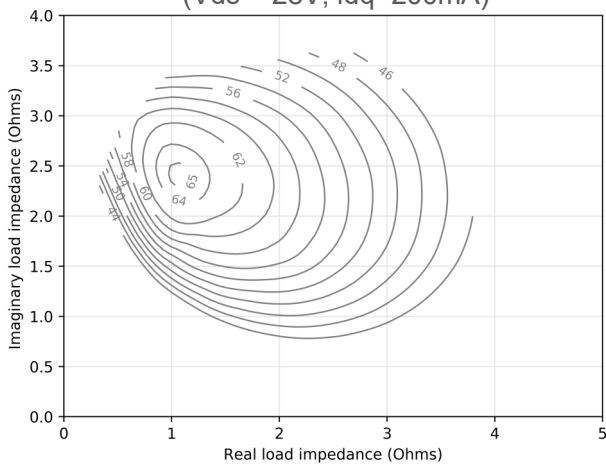
P3dB Output Power and PAE contours
(Vds = 28V, idq=200mA, Z0=50ohms)



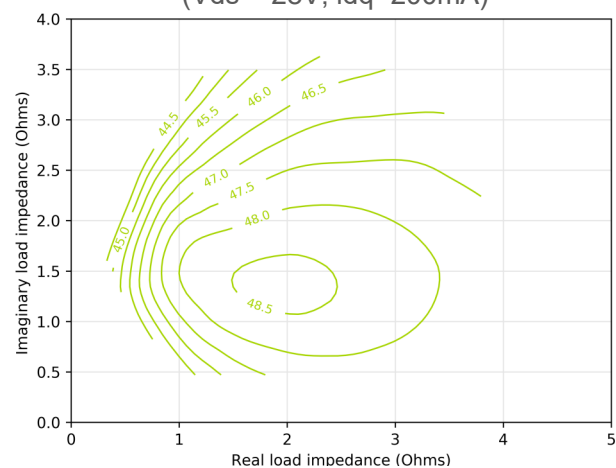
Max PAE = 65%
at Zload = 1.1+j2.4 ohms

Max Power = 48.6dBm
at Zload = 2+j1.4 ohms

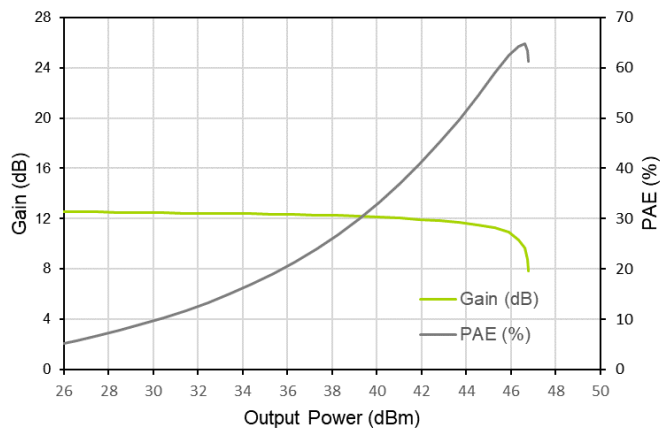
P3dB PAE contours
(Vds = 28V, idq=200mA)



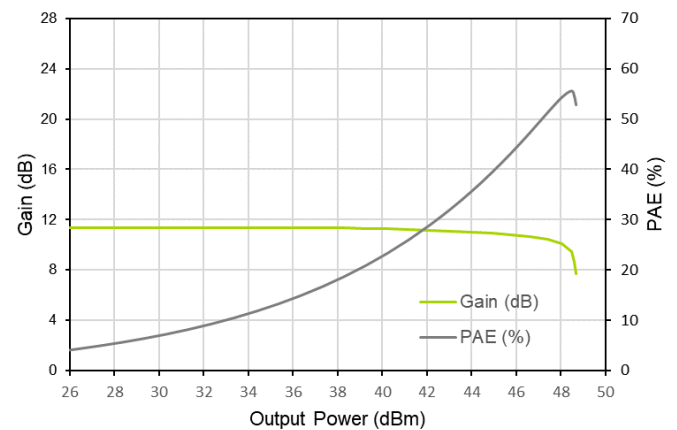
P3dB Output Power contours
(Vds = 28V, idq=200mA)



Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max PAE tune)

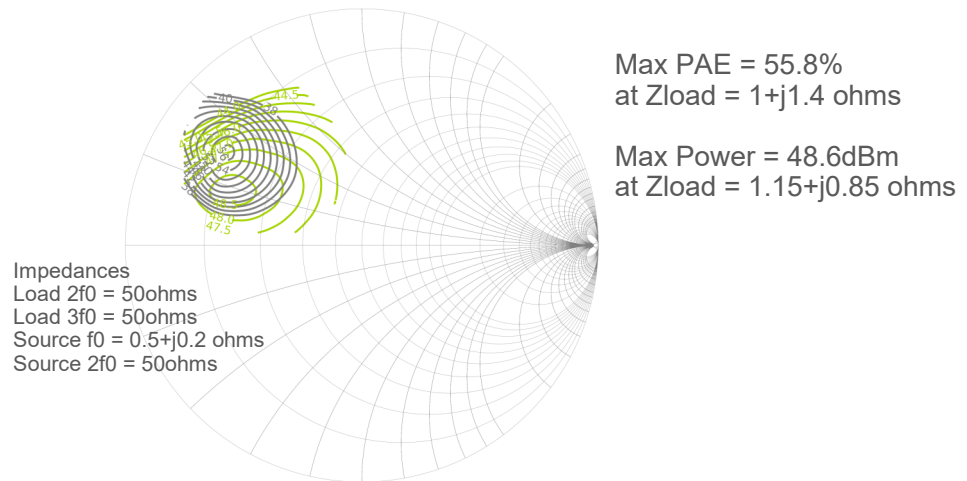


Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max Power tune)

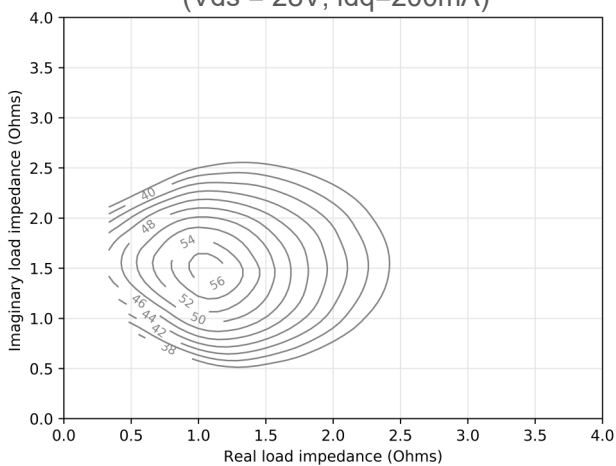


Model Load Pull Data 14GHz

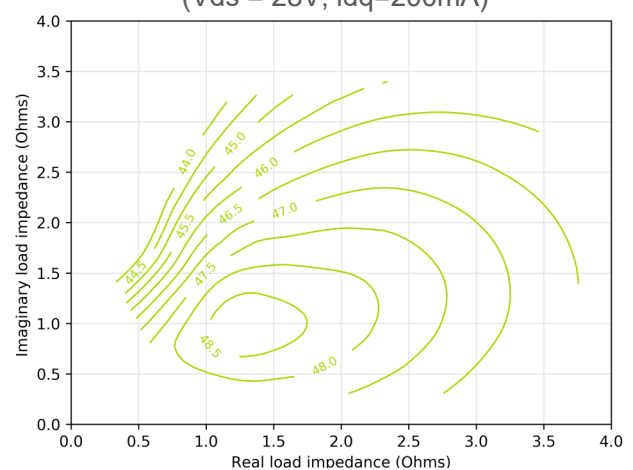
P3dB Output Power and PAE contours
(Vds = 28V, idq=200mA, Z0=50ohms)



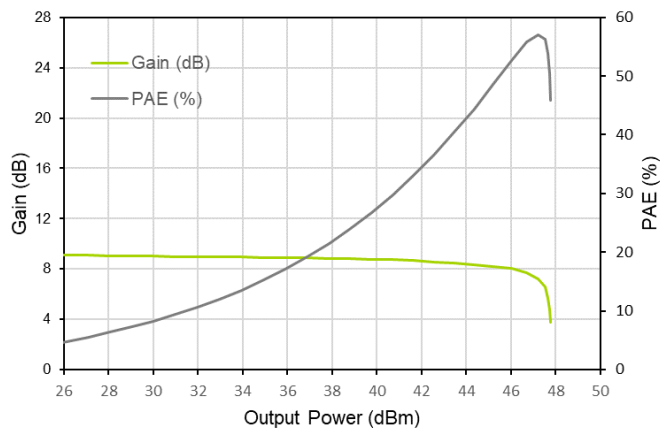
P3dB PAE contours
(Vds = 28V, idq=200mA)



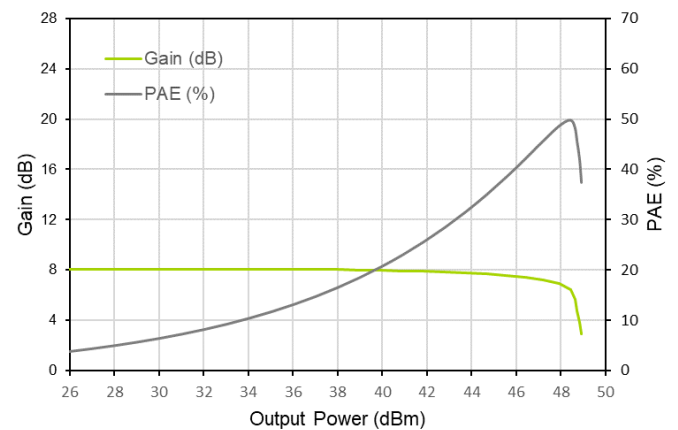
P3dB Output Power contours
(Vds = 28V, idq=200mA)



Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max PAE tune)



Gain and PAE vs Output Power
(Vds=28V, idq=200mA, Max Power tune)



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